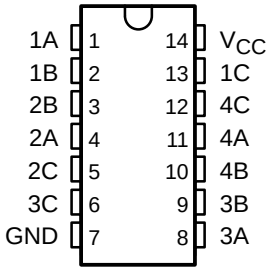
- **High Degree of Linearity**
- **High On-Off Output Voltage Ratio**
- **Low Crosstalk Between Switches**
- **Low On-State Impedance . . . 50-Ω TYP at V_{CC} = 6 V**
- **Individual Switch Controls**
- **Extremely Low Input Current**

D, DB, N, NS, OR PW PACKAGE
(TOP VIEW)



description

The SN74HC4066 is a silicon-gate CMOS quadruple analog switch designed to handle both analog and digital signals. Each switch permits signals with amplitudes of up to 6 V (peak) to be transmitted in either direction.

Each switch section has its own enable input control (C). A high-level voltage applied to C turns on the associated switch section.

Applications include signal gating, chopping, modulation or demodulation (modem), and signal multiplexing for analog-to-digital and digital-to-analog conversion systems.

ORDERING INFORMATION

T_A	PACKAGE†		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	PDIP – N	Tube	SN74HC4066N	SN74HC4066N
	SOIC – D	Tube	SN74HC4066D	HC4066
		Tape and reel	SN74HC4066DR	
	SOP – NS	Tape and reel	SN74HC4066NSR	HC4066
	SSOP – DB	Tape and reel	SN74HC4066DBR	HC4066
	TSSOP – PW	Tape and reel	SN74HC4066PWR	HC4066

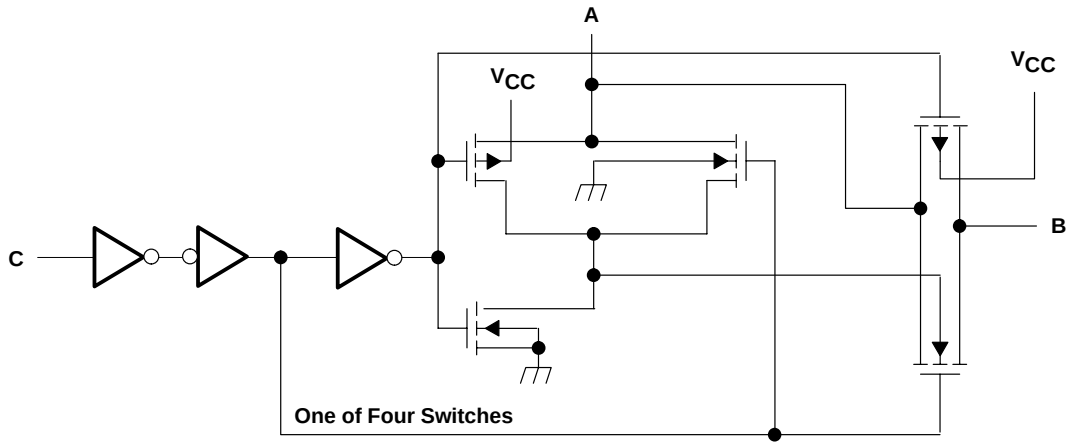
† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTION TABLE
(each switch)

INPUT CONTROL (C)	SWITCH
L	OFF
H	ON

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

logic diagram, each switch (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V_{CC} (see Note 1)	–0.5 V to 7 V
Control-input diode current, I_I ($V_I < 0$ or $V_I > V_{CC}$)	±20 mA
I/O port diode current, I_I ($V_I < 0$ or $V_{I/O} > V_{CC}$)	±20 mA
On-state switch current ($V_{I/O}$ = 0 to V_{CC})	±25 mA
Continuous current through V_{CC} or GND	±50 mA
Package thermal impedance, θ_{JA} (see Note 2): D package	86°C/W
DB package	96°C/W
N package	80°C/W
NS package	76°C/W
PW package	113°C/W
Storage temperature range, T_{stg}	–65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltages are with respect to ground unless otherwise specified.
2. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 3)

			MIN	NOM	MAX	UNIT
V_{CC}	Supply voltage		2†	5	6	V
$V_{I/O}$	I/O port voltage		0		V_{CC}	V
V_{IH}	High-level input voltage, control inputs	V_{CC} = 2 V	1.5		V_{CC}	V
		V_{CC} = 4.5 V	3.15		V_{CC}	
		V_{CC} = 6 V	4.2		V_{CC}	
V_{IL}	Low-level input voltage, control inputs	V_{CC} = 2 V	0		0.3	V
		V_{CC} = 4.5 V	0		0.9	
		V_{CC} = 6 V	0		1.2	
$\Delta t/\Delta v$	Input transition rise/fall time	V_{CC} = 2 V			1000	ns
		V_{CC} = 4.5 V			500	
		V_{CC} = 6 V			400	
T_A	Operating free-air temperature		–40		85	°C

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

† With supply voltages at or near 2 V, the analog switch on-state resistance becomes very nonlinear. It is recommended that only digital signals be transmitted at these low supply voltages.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER			TEST CONDITIONS	V_{CC}	T_A = 25°C			MIN	MAX	UNIT
					MIN	TYP	MAX			
R_{on}	On-state switch resistance		I_T = –1 mA, V_I = 0 to V_{CC}, V_C = V_{IH} (see Figure 1)	2 V		150				Ω
				4.5 V		50	85		106	
				6 V		30				
$R_{on(p)}$	Peak on resistance		V_I = V_{CC} or GND, V_C = V_{IH}, I_T = –1 mA	2 V		320				Ω
				4.5 V		70	170		215	
				6 V		50				
I_I	Control input current		V_C = 0 or V_{CC}	6 V		±0.1	±100		±1000	nA
I_{soff}	Off-state switch leakage current		V_I = V_{CC} or 0, V_O = V_{CC} or 0, V_C = V_{IL} (see Figure 2)	6 V			±0.1		±5	µA
I_{son}	On-state switch leakage current		V_I = V_{CC} or 0, V_C = V_{IH} (see Figure 3)	6 V			±0.1		±5	µA
I_{CC}	Supply current		V_I = 0 or V_{CC}, I_O = 0	6 V			2		20	µA
C_i	Input capacitance	A or B		5 V		9				pF
		C				3	10		10	
C_f	Feedthrough capacitance	A to B	V_I = 0			0.5				pF
C_o	Output capacitance	A or B		5 V		9				pF

switching characteristics over recommended operating free-air temperature range

PARAMETER		FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	V_{CC}	T_A = 25°C			MIN	MAX	UNIT
						MIN	TYP	MAX			
t_{PLH}, t_{PHL}	Propagation delay time	A or B	B or A	C_L = 50 pF (see Figure 4)	2 V		10	60		75	ns
					4.5 V		4	12		15	
					6 V		3	10		13	
t_{PZH}, t_{PZL}	Switch turn-on time	C	A or B	R_L = 1 kΩ, C_L = 50 pF (see Figure 5)	2 V		70	180		225	ns
					4.5 V		21	36		45	
					6 V		18	31		38	
t_{PLZ}, t_{PHZ}	Switch turn-off time	C	A or B	R_L = 1 kΩ, C_L = 50 pF (see Figure 5)	2 V		50	200		250	ns
					4.5 V		25	40		50	
					6 V		22	34		43	
f_I	Control input frequency	C	A or B	C_L = 15 pF, R_L = 1 kΩ, V_C = V_{CC} or GND, V_O = V_{CC}/2 (see Figure 6)	2 V		15				MHz
					4.5 V		30				
					6 V		30				
	Control feedthrough noise	C	A or B	C_L = 50 pF, R_{in} = R_L = 600 Ω, V_C = V_{CC} or GND, f_{in} = 1 MHz (see Figure 7)	4.5 V		15				mV (rms)
					6 V		20				

operating characteristics, V_{CC} = 4.5 V, T_A = 25°C

PARAMETER		TEST CONDITIONS		TYP	UNIT
C_{pd}	Power dissipation capacitance per gate	C_L = 50 pF,	f = 1 MHz	45	pF
	Minimum through bandwidth, A to B or B to A† [20 log (V_O/V_I)] = –3 dB	C_L = 50 pF, V_C = V_{CC}	R_L = 600 Ω, (see Figure 8)	30	MHz
	Crosstalk between any switches‡	C_L = 10 pF, f_{in} = 1 MHz	R_L = 50 Ω, (see Figure 9)	45	dB
	Feedthrough, switch off, A to B or B to A‡	C_L = 50 pF, f_{in} = 1 MHz	R_L = 600 Ω, (see Figure 10)	42	dB
	Amplitude distortion rate, A to B or B to A	C_L = 50 pF, f_{in} = 1 kHz	R_L = 10 kΩ, (see Figure 11)	0.05%	

† Adjust the input amplitude for output = 0 dBm at f = 1 MHz. Input signal must be a sine wave.
‡ Adjust the input amplitude for input = 0 dBm at f = 1 MHz. Input signal must be a sine wave.

PARAMETER MEASUREMENT INFORMATION

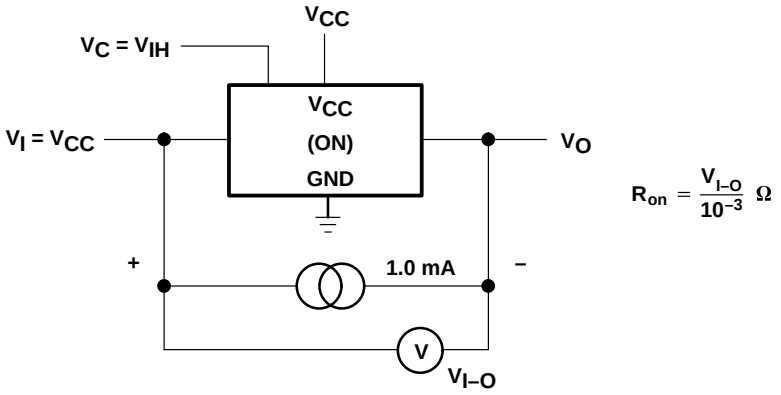
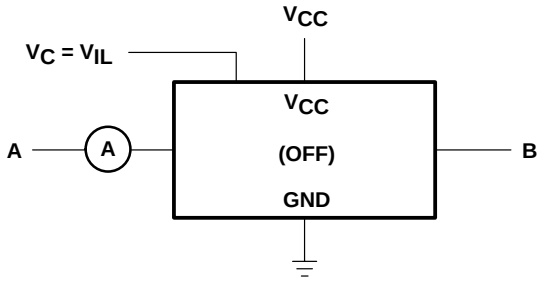


Figure 1. On-State Resistance Test Circuit



$V_S = V_A - V_B$
CONDITION 1: $V_A = 0$, $V_B = V_{CC}$
CONDITION 2: $V_A = V_{CC}$, $V_B = 0$

Figure 2. Off-State Switch Leakage Current Test Circuit

PARAMETER MEASUREMENT INFORMATION

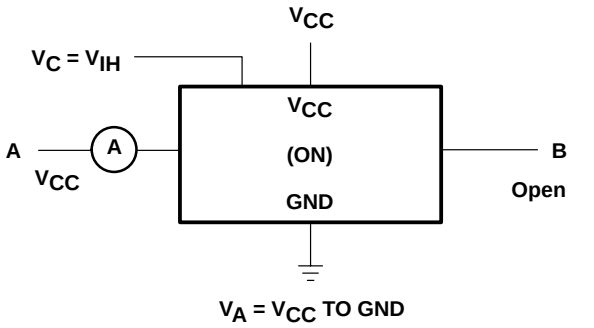


Figure 3. On-State Leakage Current Test Circuit

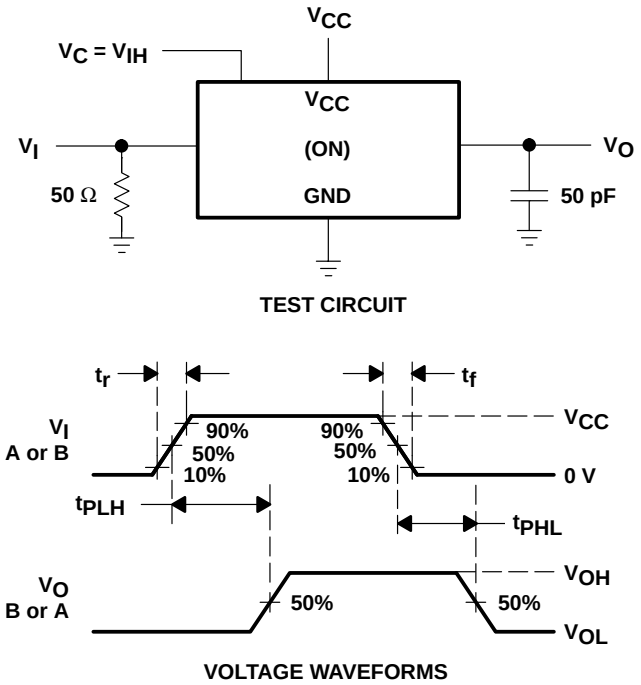
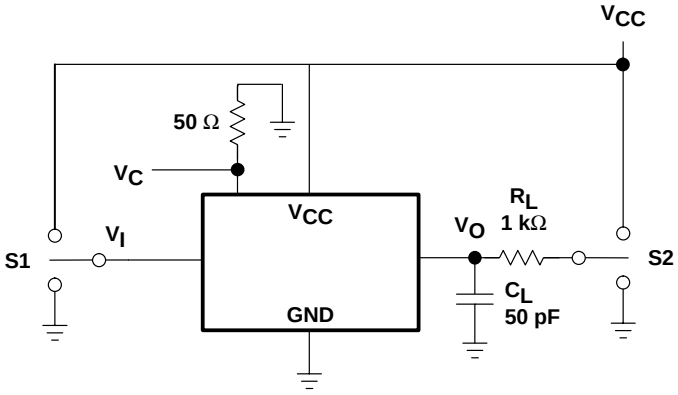


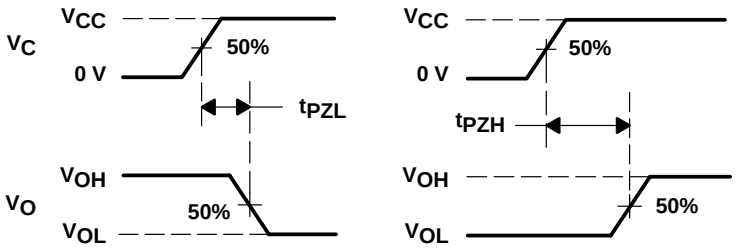
Figure 4. Propagation Delay Time, Signal Input to Signal Output

PARAMETER MEASUREMENT INFORMATION

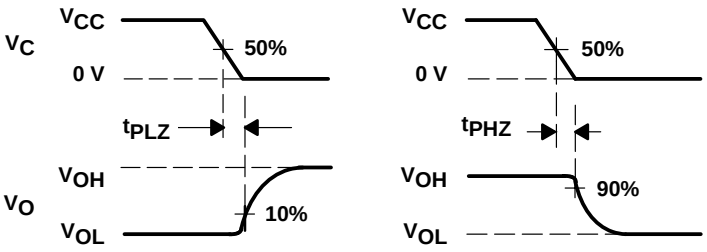


TEST	S1	S2
t_{PZL}	GND	V_{CC}
t_{PZH}	V_{CC}	GND
t_{PLZ}	GND	V_{CC}
t_{PHZ}	V_{CC}	GND

TEST CIRCUIT



(t_{PZL}, t_{PZH})



(t_{PLZ}, t_{PHZ})

VOLTAGE WAVEFORMS

Figure 5. Switching Time (t_{PZL}, t_{PLZ}, t_{PZH}, t_{PHZ}), Control to Signal Output

PARAMETER MEASUREMENT INFORMATION

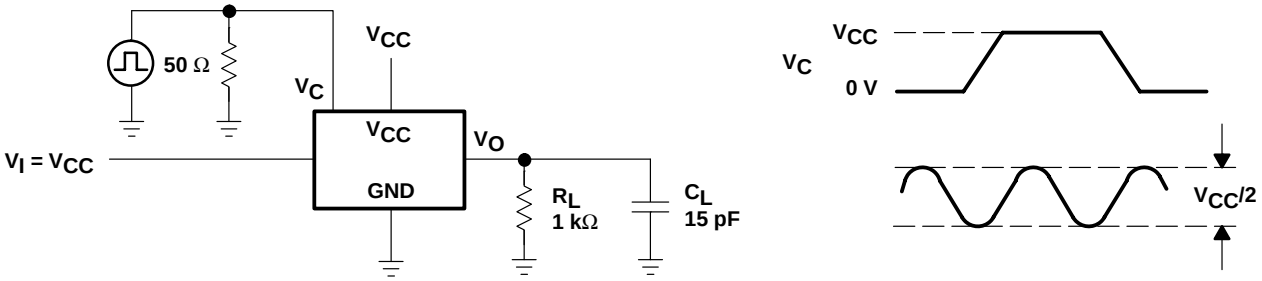


Figure 6. Control Input Frequency

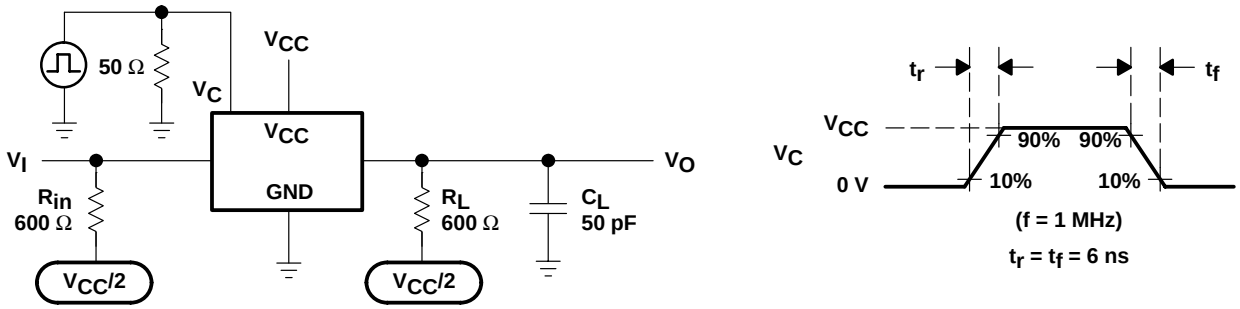


Figure 7. Control Feedthrough Noise

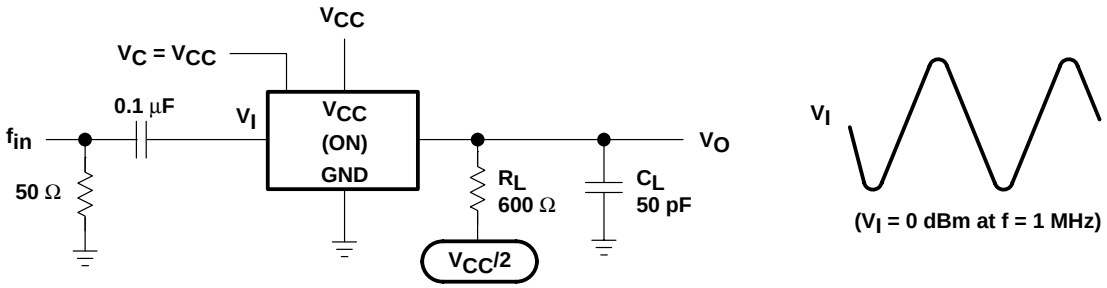


Figure 8. Minimum Through Bandwidth

PARAMETER MEASUREMENT INFORMATION

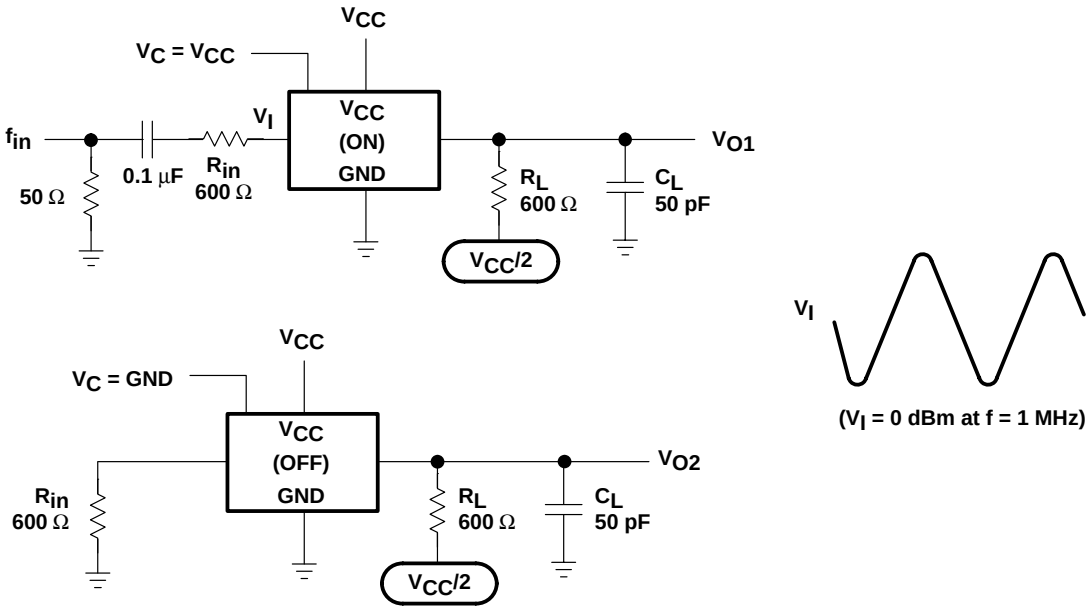


Figure 9. Crosstalk Between Any Two Switches

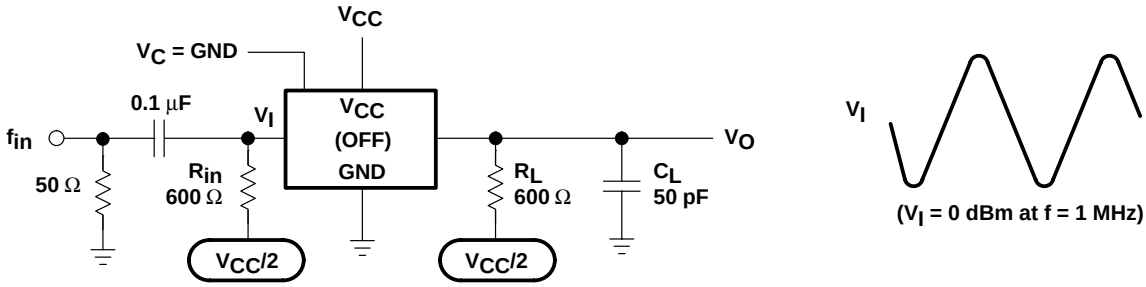


Figure 10. Feedthrough, Switch Off

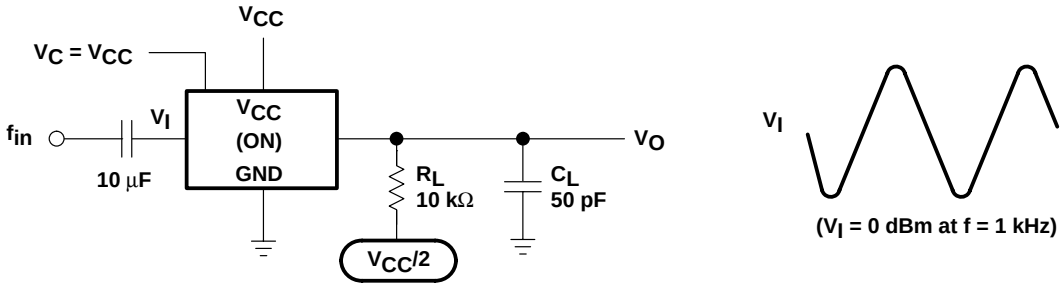


Figure 11. Amplitude Distortion Rate

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